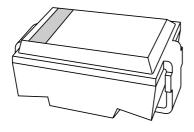
DISCRETE SEMICONDUCTORS

DATA SHEET



BZG04 seriesTransient voltage suppressor diodes

Product specification Supersedes data of 1996 Sep 19 2002 Jul 04





Transient voltage suppressor diodes

BZG04 series

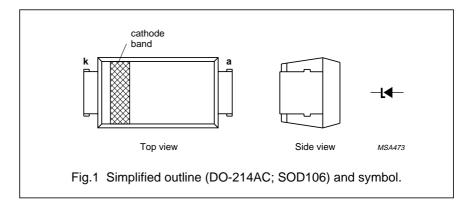
FEATURES

- · Glass passivated
- High maximum operating temperature
- Low leakage current
- · Excellent stability
- UL 94V-O classified plastic package
- Transient suppressor stand-off voltage range:
 8.2 to 220 V for 32 types
- Shipped in 12 mm embossed tape.

DESCRIPTION

DO-214AC surface mountable package with glass passivated chip.

The well-defined void-free case is of a transfer-moulded thermo-setting plastic.



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
P _{RSM}	non-repetitive peak reverse power dissipation	10/1000 μs exponential pulse (see Fig.4); $T_j = 25$ °C prior to surge; see also Fig.2	_	300	W
T _{stg}	storage temperature		-65	+175	°C
Tj	junction temperature		-65	+175	°C

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ELECTRICAL CHARACTERISTICS

Total series

 $T_j = 25$ °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _F	forward voltage	I _F = 0.5 A; see Fig.3	_	1.2	V

Per type

 $T_j = 25$ °C unless otherwise specified.

TYPE	REVERSE BREAKDOWN VOLTAGE		RATURE	TEST CURRENT	CLAMPING VOLTAGE REVERSE CURR at STAND-OF			ND-OFF
NUMBER	V _{(BR)R} (V) at I _{test}	S _Z (%/k	() at I _{test}	I _{test} – (mA)	V _{(CL)R} (V)	at I _{RSM} (A)	I _R (μ A)	at V _R
	MIN.	MIN.	MAX.	(,	MAX.		MAX.	(-,
BZG04-8V2	9.4	0.05	0.09	50	14.8	20.3	20	8.2
BZG04-9V1	10.4	0.05	0.10	50	15.7	19.1	5	9.1
BZG04-10	11.4	0.05	0.10	50	17.0	17.7	5	10
BZG04-11	12.4	0.05	0.10	50	18.9	15.9	5	11
BZG04-12	13.8	0.05	0.10	50	20.9	14.4	5	12
BZG04-13	15.3	0.06	0.11	25	22.9	13.1	5	13
BZG04-15	16.8	0.06	0.11	25	25.6	11.7	5	15
BZG04-16	18.8	0.06	0.11	25	28.4	10.6	5	16
BZG04-18	20.8	0.06	0.11	25	31.0	9.7	5	18
BZG04-20	22.8	0.06	0.11	25	33.8	8.9	5	20
BZG04-22	25.1	0.06	0.11	25	38.1	7.9	5	22
BZG04-24	28	0.06	0.11	25	42.2	7.1	5	24
BZG04-27	31	0.06	0.11	25	46.2	6.5	5	27
BZG04-30	34	0.06	0.11	10	50.1	6.0	5	30
BZG04-33	37	0.06	0.11	10	54.1	5.5	5	33
BZG04-36	40	0.07	0.12	10	60.7	4.9	5	36
BZG04-39	44	0.07	0.12	10	65.5	4.6	5	39
BZG04-43	48	0.07	0.12	10	70.8	4.2	5	43
BZG04-47	52	0.07	0.12	10	78.6	3.8	5	47
BZG04-51	58	0.08	0.13	10	86.5	3.5	5	51
BZG04-56	64	0.08	0.13	10	94.4	3.2	5	56
BZG04-62	70	0.08	0.13	10	103.5	2.9	5	62
BZG04-68	77	0.08	0.13	10	114	2.6	5	68
BZG04-75	85	0.09	0.13	5	126	2.4	5	75
BZG04-82	94	0.09	0.13	5	139	2.2	5	82
BZG04-91	104	0.09	0.13	5	152	2.0	5	91
BZG04-100	114	0.09	0.13	5	167	1.8	5	100
BZG04-110	124	0.09	0.13	5	185	1.6	5	110
BZG04-120	138	0.09	0.13	5	204	1.5	5	120
BZG04-130	153	0.09	0.13	5	224	1.3	5	130

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TYPE	REVERSE BREAKDOWN VOLTAGE	TEMPEI COEFF	RATURE	TEST CURRENT	CLAMPING	S VOLTAGE	at STAI	CURRENT ND-OFF TAGE	
NUMBER	V _{(BR)R} (V) at I _{test}	S _Z (%/K	() at I _{test}	l _{test}	V _{(CL)R} (V)	at I _{RSM} (A)	I _R (μ A)	at V _R	
	MIN.	MIN.	MAX.	(mA)	MAX.	1 Hote I	MAX.	(*)	
BZG04-150	168	0.09	0.13	5	249	1.2	5	150	
BZG04-160	188	0.09	0.13	5	276	1.1	5	160	
BZG04-180	208	0.09	0.13	2	305	1.0	5	180	
BZG04-200	228	0.09	0.13	2	336	0.9	5	200	
BZG04-220	251	0.09	0.13	2	380	0.8	5	220	

Note

1. Non-repetitive peak reverse current in accordance with "IEC 60-1, Section 8" (10/1000 μs pulse); see Fig.4.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-tp}	thermal resistance from junction to tie-point		25	K/W
R _{th j-a}	thermal resistance from junction to ambient	note 1	100	K/W
		note 2	150	K/W

Notes

- 1. Device mounted on an Al_2O_3 printed-circuit board, 0.7 mm thick; thickness of Cu-layer \geq 35 μ m, see Fig.5.
- 2. Device mounted on an epoxy-glass printed-circuit board, 1.5 mm thick; thickness of Cu-layer \geq 40 μ m, see Fig.5. For more information please refer to the "General Part of associated Handbook".

2002 Jul 04

Transient voltage suppressor diodes

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GRAPHICAL DATA

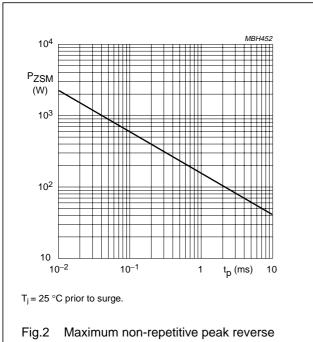
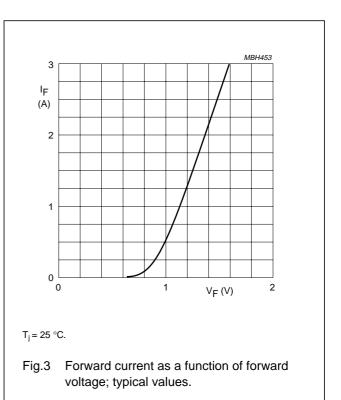
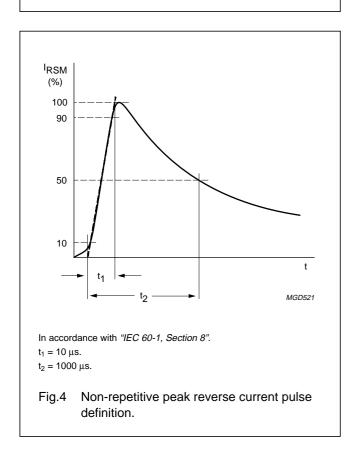
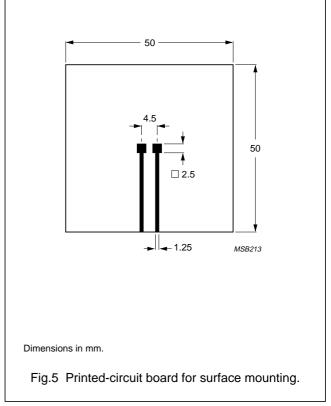


Fig.2 Maximum non-repetitive peak reverse power dissipation as a function of pulse duration (square pulse).







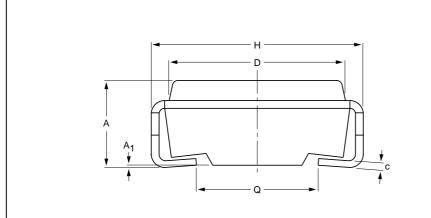
Transient voltage suppressor diodes

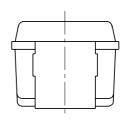
BZG04 series

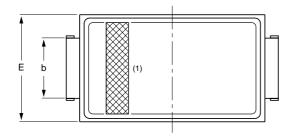
PACKAGE OUTLINE

Transfer-moulded thermo-setting plastic small rectangular surface mounted package; 2 connectors

SOD106









DIMENSIONS (mm are the original dimensions)

UNIT	Α	A ₁	b	С	D	E	н	Q
mm	2.3 2.0	0.05	1.6 1.4	0.2	4.5 4.3	2.8 2.4	5.5 5.1	3.3 2.7

Note

1. The marking band indicates the cathode.

OUTLINE		REFER	ENCES	EUROPEAN ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE	
SOD106		DO-214AC			97-06-09	

Transient voltage suppressor diodes

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DATA SHEET STATUS

DATA SHEET STATUS(1)	PRODUCT STATUS ⁽²⁾	DEFINITIONS
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